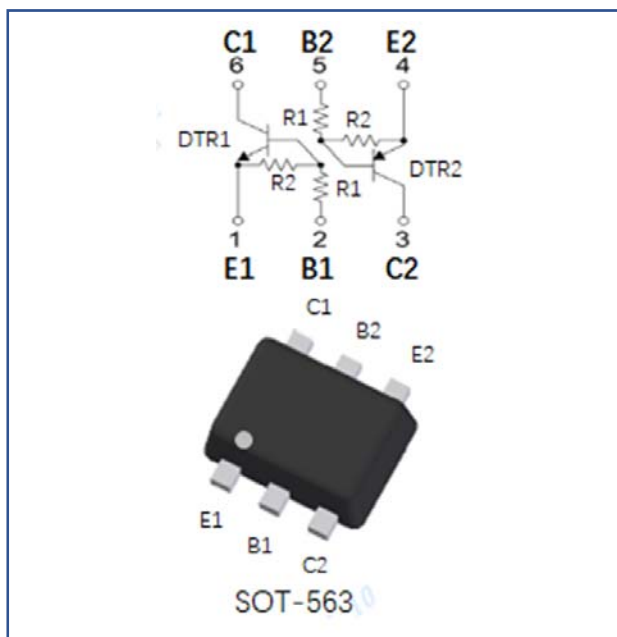


NPN+PNP Digital Transistors (Built-in Resistors)



Features

- Moisture sensitivity level 1
- Halogen free and RoHS compliant
- Surface mount package ideally suited for automatic Insertion

Application

- Signal amplification
- Switching circuit

Mechanical data

- **Package:** SOT-563
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102

■ Maximum Ratings ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

DTR1-NPN

Item	Symbol	Unit	Conditions	Value
Device marking code				D2
Supply voltage	V_{CC}	V		50
Input voltage	V_{IN}	V		-10 to +40
Output current	I_O	mA		100
Power dissipation	P_D	mW		150
Junction temperature	T_J	$^{\circ}\text{C}$		-55 to +150
Storage temperature	T_{STG}	$^{\circ}\text{C}$		-55 to +150



DTR2-PNP

Item	Symbol	Unit	Conditions	Value
Supply voltage	V_{CC}	V		-50
Input voltage	V_{IN}	V		-40 to +10
Output current	I_O	mA		-100
Power dissipation	P_D	mW		150
Junction temperature	T_J	°C		-55 to +150
Storage temperature	T_{STG}	°C		-55 to +150

■ Electrical Characteristics ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

DTR1-NPN

Item	Symbol	Unit	Conditions	Min	Typ	Max
Input voltage	$V_{I(off)}$	V	$V_{CC}=5V, I_c=100\mu A$	0.5		
	$V_{I(on)}$	V	$V_O=0.2V, I_c=5mA$			3
Output voltage	$V_{O(on)}$	V	$I_O / I_i = 10mA / 0.5 mA$			0.3
Input current	I_I	mA	$V_i=5V$			0.36
Output current	$I_{O(off)}$	μA	$V_{CC}=50V, V_i=0$			0.5
DC current gain	G_I		$V_O=5V, I_O=5mA$	56		
Input resistance	R_1	k Ω		15.4	22	28.6
Resistance ratio	R_2/R_1			0.8	1	1.2
Transition frequency	f_T	MHz	$V_{CE}=10V, I_E=5mA, f=100MHz$		250	



DTR2-PNP

Item	Symbol	Unit	Conditions	Min	Typ	Max
Input voltage	$V_{I(off)}$	V	$V_{CC}=-5V, I_c=-100\mu A$	-0.5		
	$V_{I(on)}$	V	$V_O=-0.2V, I_c=-5mA$			-3
Output voltage	$V_{O(on)}$	V	$I_O / I_i = -10mA / -0.5mA$			-0.3
Input current	I_I	mA	$V_i=-5V$			-0.36
Output current	$I_{O(off)}$	μA	$V_{CC}=-50V, V_i=0$			-0.5
DC current gain	G_I		$V_O=-5V, I_o=-5mA$	56		
Input resistance	R_1	k Ω		15.4	22	28.6
Resistance ratio	R_2/R_1			0.8	1	1.2
Transition frequency	f_T	MHz	$V_{CE}=-10V, I_E=-5mA, f=100MHz$		250	

■ Thermal Characteristics

Parameter	Symbol	Unit	Value
Thermal resistance, junction-to-ambient	$R_{\theta J-A}^{(1)}$	$^{\circ}C/W$	833
Thermal resistance, junction-to-case	$R_{\theta J-C}^{(1)}$	$^{\circ}C/W$	667

Note:

(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 25.4mm*25.4mm copper pad areas

■ Ordering Information

Preferred P/N	Packing code	Unit weight(g)	Minimum package(pcs)	Inner box quantity(pcs)	Outer carton quantity(pcs)	Delivery mode
EMD2	F2	Approximate 0.0035	3000	30000	120000	7" reel

■Characteristics

DTR1-NPN

Fig 1: Input Voltage (On) Characteristics

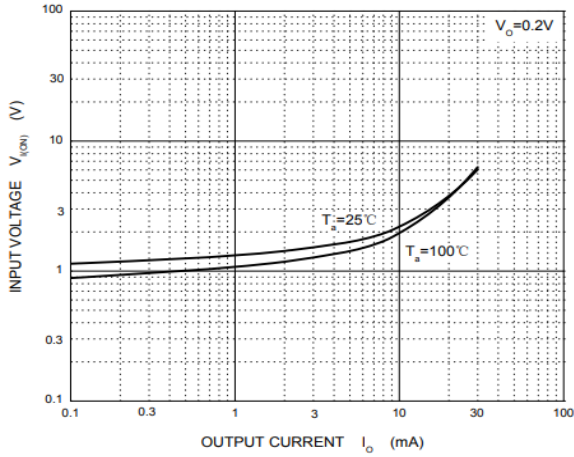


Fig 2: Input Voltage (Off) Characteristics

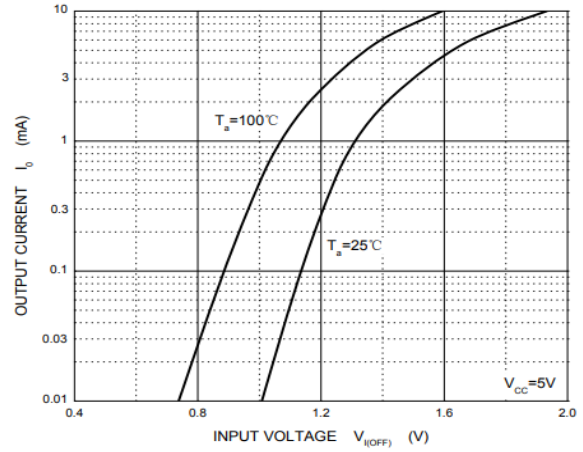


Fig 3: Output Voltage (On) Characteristics

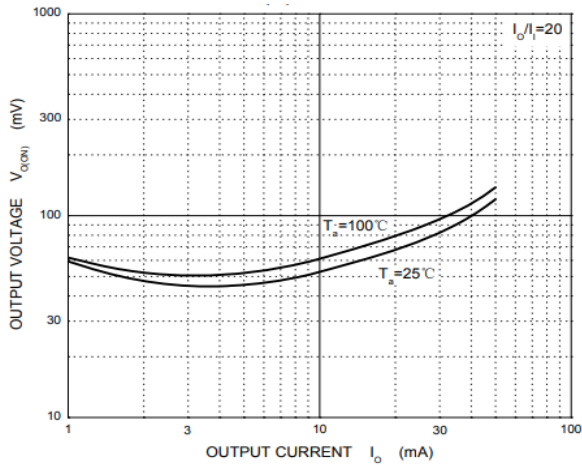


Fig 4: DC Current Gain Characteristics

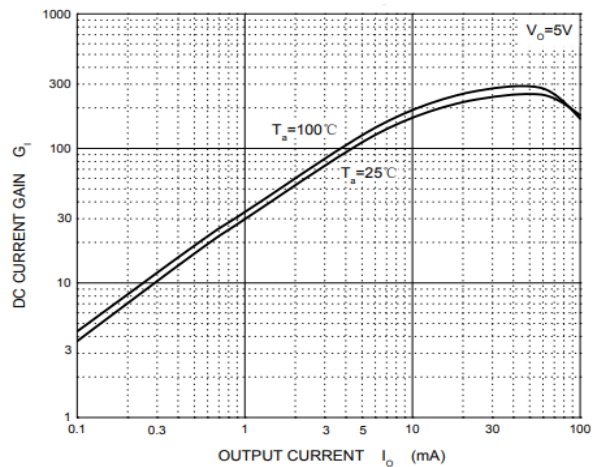
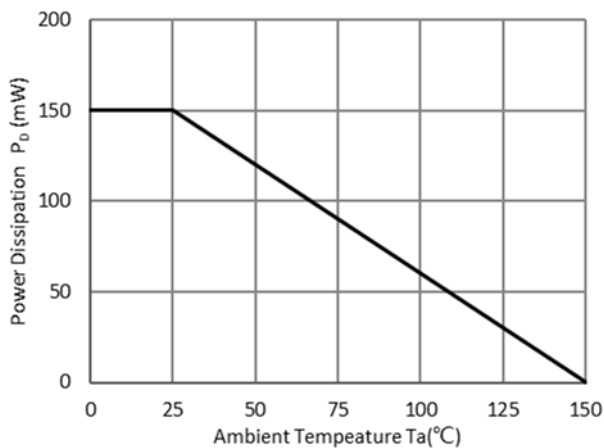


Fig 5: P_D-T_a Curve



DTR2-PNP

Fig 1: Input Voltage (On) Characteristics

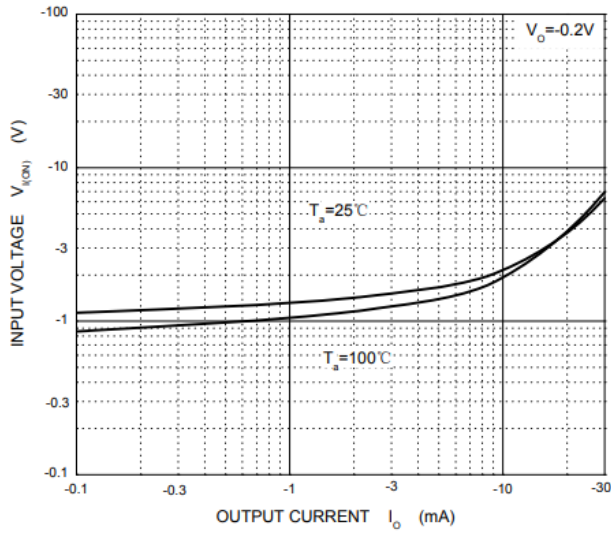


Fig 2: Input Voltage (Off) Characteristics

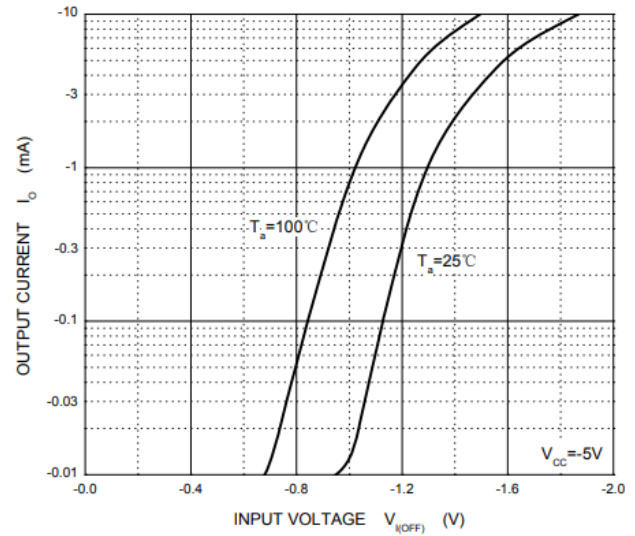


Fig 3: Output Voltage (On) Characteristics

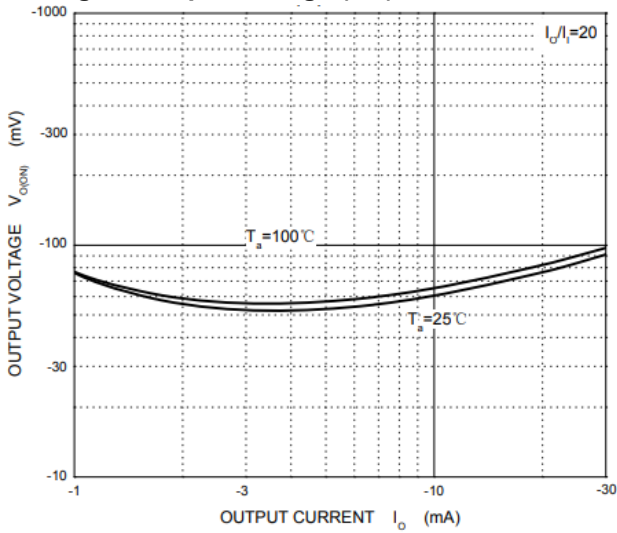


Fig 4: DC Current Gain Characteristics

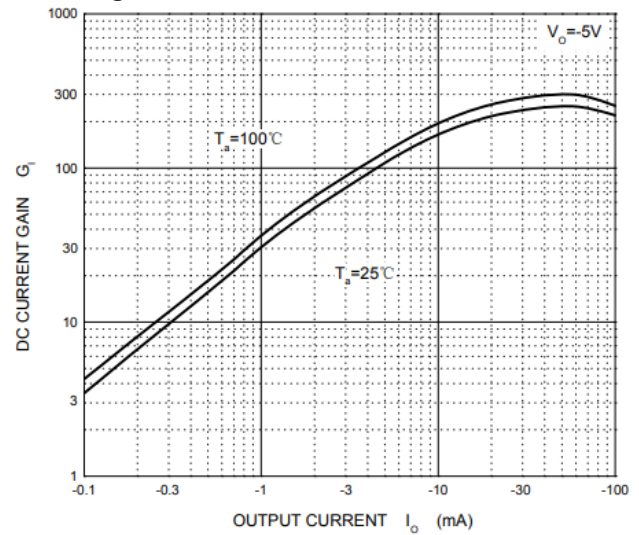
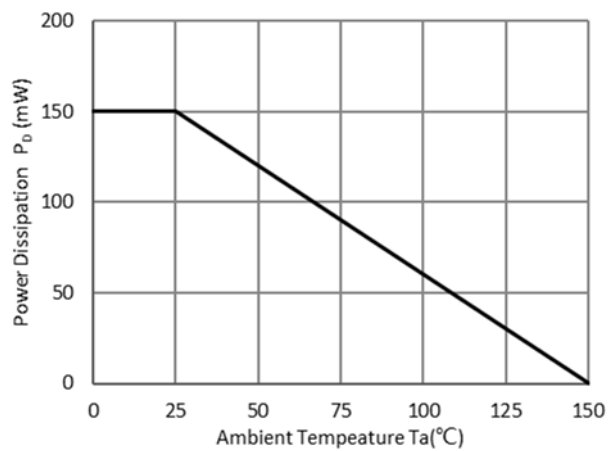
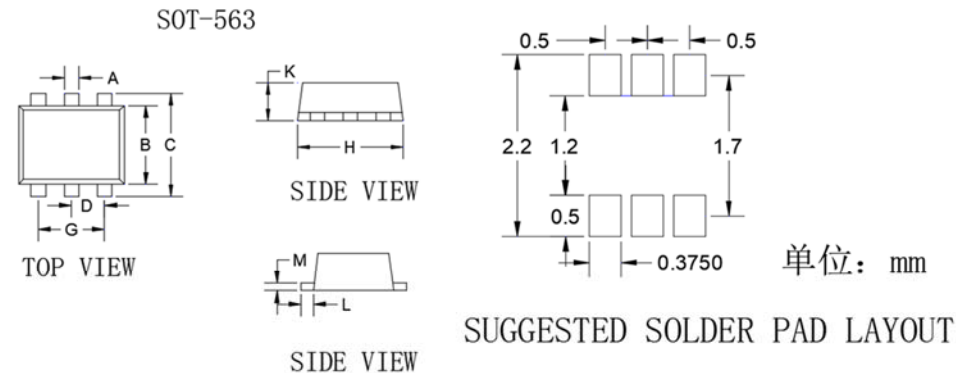


Fig 5: P_D-Ta Curve





■ Outline Dimensions



DIM	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.006	0.011	0.150	0.300
B	0.043	0.051	1.100	1.300
C	0.059	0.067	1.500	1.700
D	0.016	0.024	0.400	0.600
G	0.035	0.043	0.900	1.100
H	0.059	0.067	1.500	1.700
K	0.021	0.026	0.550	0.650
L	0.004	0.011	0.100	0.300
M	0.004	0.007	0.100	0.180

Note:

1. All dimensions are in millimeters (mm) unless otherwise specified.
[所有尺寸均以毫米为单位, 除非另有说明]
2. General tolerances: $\pm 0.10\text{mm}$ unless otherwise specified.
[通用公差为 $\pm 0.10\text{mm}$, 除非另有说明]
3. Dimensions and tolerances per ASME Y14.5M-2018.
[尺寸和公差遵循 ASME Y14.5M-2018 标准]
4. All dimensions shown are exclusive of burrs and gate residues.
Burrs and gate vestiges shall not exceed 0.15 mm in maximum.
[所有尺寸均不包括毛刺和浇口残留。毛刺与浇口残留的尺寸最大不得超过 0.15mm]
5. Dimension b does not include dambar protrusion of max 0.100 mm per side.
[尺寸b不包括单边最大0.100 MM的中筋凸出部分]
6. Dimensions B and H are the overall extreme outer dimensions of the mold compound. These dimensions exclude mold flash, lead flash, protrusions and burrs but include the maximum allowable mold mismatch.
[B和H是塑封体的外部极限尺寸, 不包括包封溢料、内引线溢料、凸出部分以及胶体毛刺, 但是包含了包封错位的最大尺寸]
7. Formed leads shall be planar with respect to one another within a maximum of 0.076 mm relative to the seating plane.
[成型的管脚应为同一平面, 共面性最大为0.1mm]
8. ★It is the key size.
[★ 标记为关键尺寸]



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